

isc Silicon NPN Power Transistor

2SC3890

DESCRIPTION

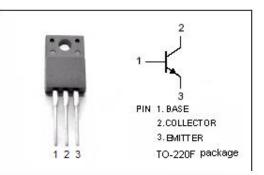
- Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= 400V(Min)
- Low Collector Saturation Voltage-
 - : $V_{CE(sat)}$ = 0.5V(Max)@ I_C= 3A
- High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

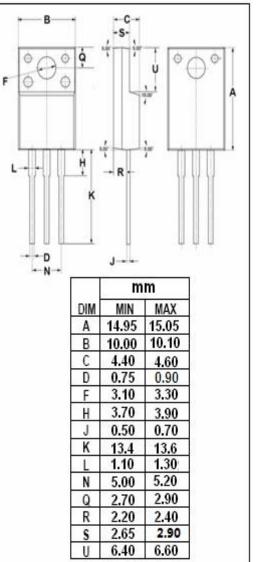
APPLICATIONS

• Designed for switching regulator and general purpose applications.

SYMBOL	PARAMETER	VALUE	UNIT				
V _{CBO}	Collector-Base Voltage	500	v				
V _{CEO}	Collector-Emitter Voltage	400	v				
V _{EBO}	Emitter-Base Voltage	10	v				
lc	Collector Current-Continuous	7	А				
I _{CM}	Collector Current-Peak	14	А				
lв	Base Current-Continuous	2	А				
Pc	Collector Power Dissipation @T _c =25℃	30	w				
TJ	Junction Temperature	150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 25mA; I _B = 0	400			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 0.6A			0.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 0.6A			1.3	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			100	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 10V; I _C = 0			100	μA
h _{FE}	DC Current Gain	I _C = 3A; V _{CE} = 4V	10		30	
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f= 1MHz		50		pF
f⊤	Current-Gain—Bandwidth Product	I _E = -0.5A; V _{CE} = 12V		10		MHz

Switching Times

t _{on}	Turn-On Time		Ic= 3A; I _{B1} = 0.3A; I _{B2} = -0.6A; V _{CC} = 200V; R _L = 66 Ω		1.0	μS
t _{stg}	Storage Time				3.0	μ S
tf	Fall Time				0.5	μs

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